

Engineering/Process Change Notice

ECN/PCN No.: 4476

For Manufacturer					
Product Description: Ceramic SMD Crystal Oscillator	Abracon Part Numb EP16E7 Series	er / Part Series:	 □ Documentation only ○ ECN ○ EOL 	⊠ Series □ Part Number	
Affected Revision: Rev. G 12/11/2012	New Revision:	DL	Application:	□ Safety ⊠ Non-Safety	
Prior to Change: ACTIVE	1				
After Change: EOL					
Cause/Reason for Change: Discontinuation of manufacturing capabilit	У				
	Chan	ge Plan			
Effective Date: 11/15/2022	Additional Remarks: N/A				
Change Declaration: N/A					
Issued Date:	Issued By:		Issued Department:		
11/15/22	Conor	Healey	Engineering		
Approval:	Approval:		Approval:		
Thomas Culhane Engineering Director	<i>Reuben Q</i> Quality		Ying Huang Purchasing Director		
	-	on EOL only	Fulchasing	Director	
Last Time Buy (if applicable):			ou / Dout Couice		
None	Alternate Part Number / Part Series: ASEDV ASE3 AP3		ASEDV, ASE3, AP3S		
Additional Approval:	Additional Approval		Additional Approval:		
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Customer Approval (If Applicable)					
Qualification Status:					
□ Approved □ Not accepted					
Note: It is considered approved if there is n	o feedback from the c	ustomer 1 month afte	r ECN/PCN is released.		
Customer Part Number:		Customer Project:			
Company Name:	Company Represent	ative:	Representative Signate	ıre:	
Customer Remarks:					

Form #7020 | Rev. G | Effective: 02/22/2021 |

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EP16E7 Series



REGULATORY COMPLIANCE

Lead Free	EU RoHS	China RoHS	REACH
	2011/65 + 2015/863	e	SVHC
COMPLIANT	COMPLIANT	COMPLIANT	COMPLIANT



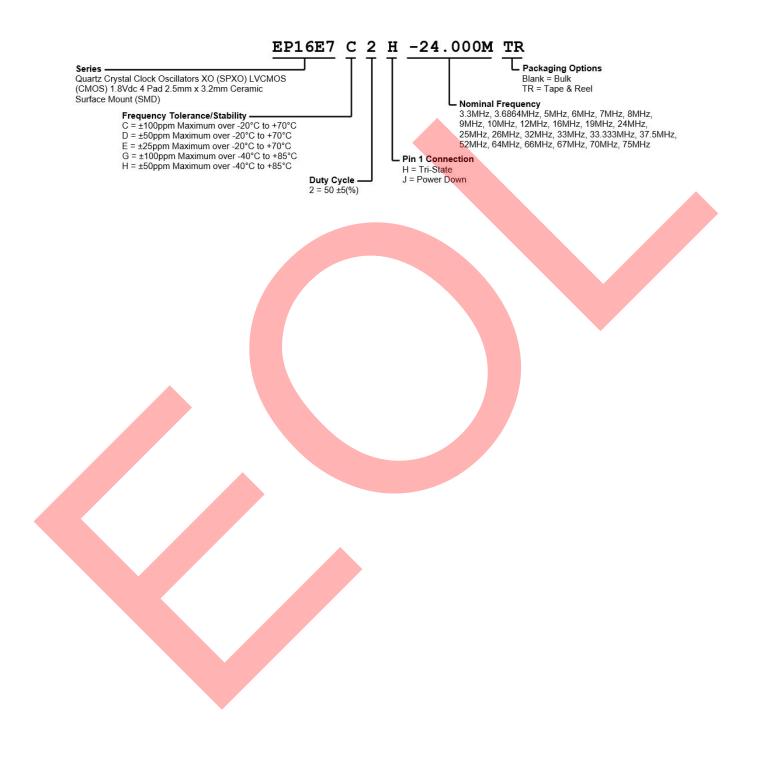
ITEM DESCRIPTION

Quartz Crystal Clock Oscillators XO (SPXO) LVCMOS (CMOS) 1.8Vdc 4 pad 2.5mm x 3.2mm Ceramic Surface Mount (SMD)

ELECTRICAL SPECIFICAT		
Nominal Frequency	3.3MHz to 75MHz	
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 260°C Reflow, Shock, and Vibration ±100ppm Maximum over -20°C to +70°C ±50ppm Maximum over -20°C to +70°C ±25ppm Maximum over -20°C to +70°C ±100ppm Maximum over -40°C to +85°C ±50ppm Maximum over -40°C to +85°C	
Aging at 25°C	±5ppm/year Maximum	
Supply Voltage	1.8Vdc ±5%	
Input Current	8mA Maximum over Nominal Frequency of 3.3MHz to 25MHz 9mA Maximum over Nominal Frequency of 25.000001MHz to 50MHz 12mA Maximum over Nominal Frequency of 50.000001MHz to 75MHz	
Output Voltage Logic High (V _{он})	IOH = -8mA 90% of Vdd Minimum	
Output Voltage Logic Low (V _{oL})	IOL = +8mA 10% of Vdd Maximum	
Rise/Fall Time	Measured at 2 <mark>0% to 8</mark> 0% of waveform 6nSec Maximu <mark>m over N</mark> ominal Frequency of 3.3MHz to 50MHz 4nSec Maximum over Nominal Frequency of 50.000001MHz to 75MHz	
Duty Cycle	Measured at 50% of waveform 50 ±5(%)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Pin 1 Connection	Tri-State Power Down	
Pin 1 Input Voltage (Vih and Vil)	90% of Vdd Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output	
Standby Current	<mark>30µA Ma</mark> ximum (Pin 1 = Ground, Power Down)	
Disable Current	4mA Maximum (Pin 1 = Ground, Tri-State)	
Absolute Clock Jitter	350pSec Maximum over No <mark>minal Fr</mark> equency of 3.3MHz to 24.999999MHz 200pSec Maximum over Nominal Frequency of 25MHz to 75MHz	
Start Up Time	10mSec Maximum	
Storage Temperature Range	-55°C to 125°C	

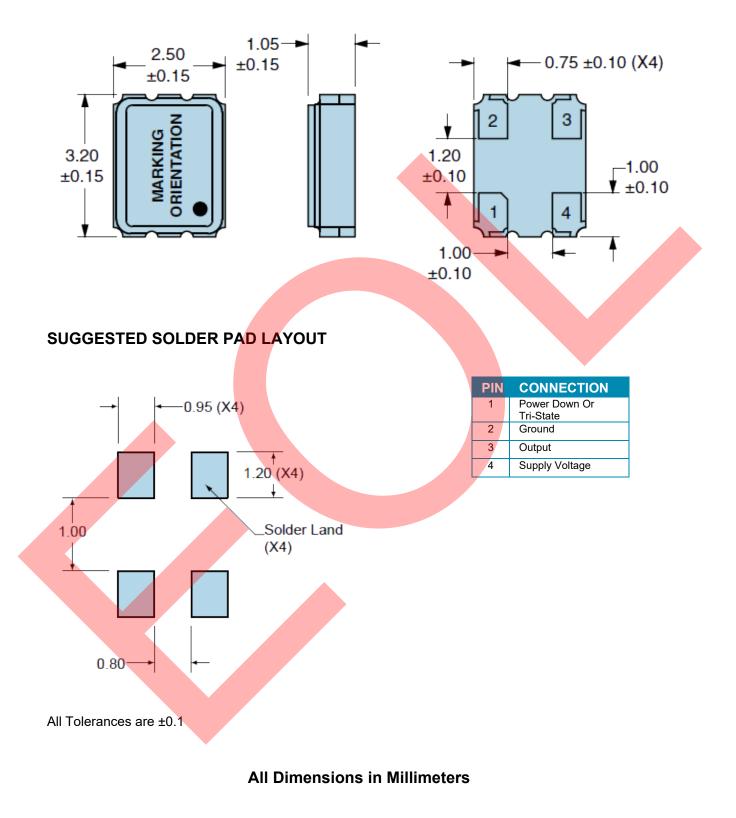


PART NUMBERING GUIDE



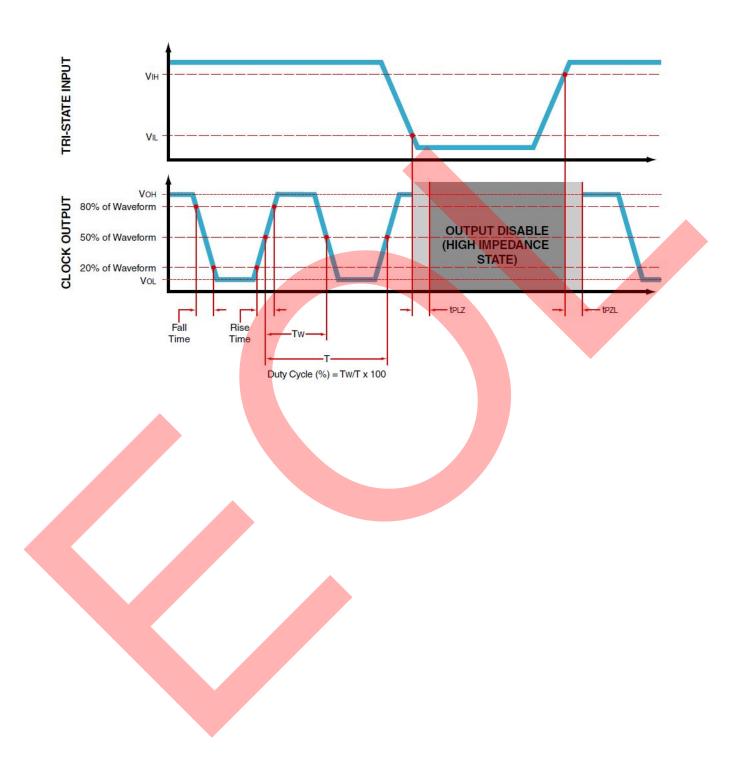


MECHANICAL DIMENSIONS



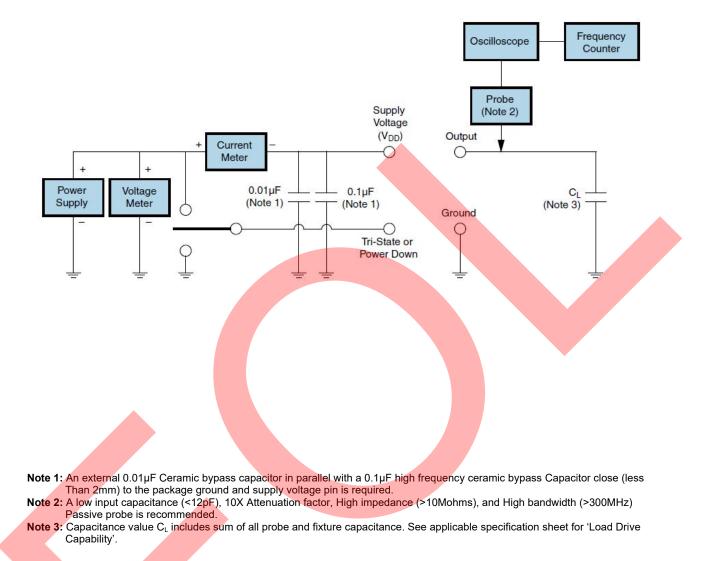


OUTPUT WAVEFORM & TIMING DIAGRAM





TEST CIRCUIT FOR CMOS OUTPUT



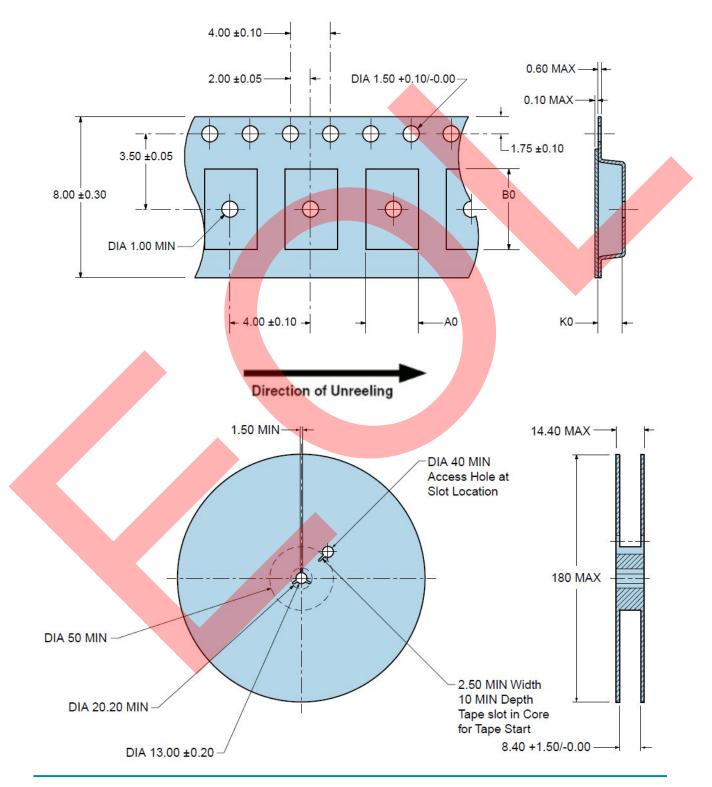
EP16E7 Series



TAPE & REEL DIMENSIONS

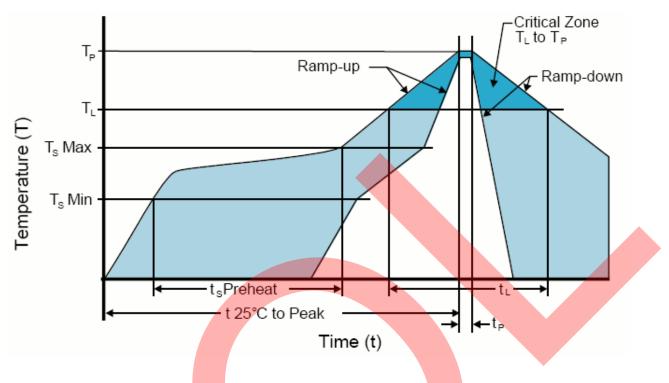
Quantity per Reel: 1,000 Units All Dimensions in Millimeters

Compliant to EIA-481





RECOMMENDED SOLDER REFLOW METHOD



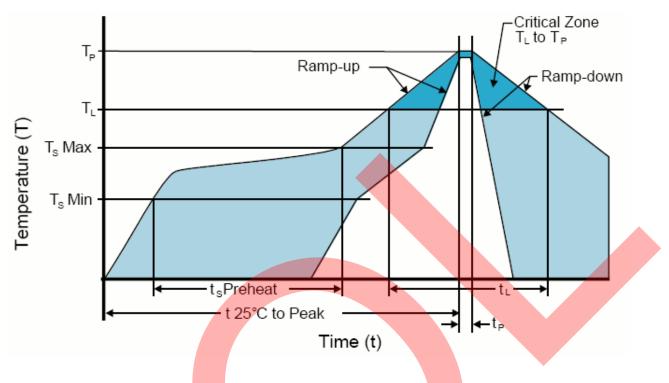
HIGH TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	150°C	
- Temperature Typical (Ts TYP)	175°C	
	200°C	
- Time (t _s MIN)	60 - 180 Seconds	
Ramp-up Rate (T _L to T _P)	3°C/Second Maximum	
Time Maintained Above:		
· • · · · · · · · · · · · · · · · · · ·	217°C	
- Time (t _L)	60 - 150 Seconds	
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(T _P Target)	250°C +0/-5°C	
Time within 5°C of actual peak (t _p)	20 - 4 <mark>0 Seconds</mark>	
Ramp-down Rate	6° <mark>C/Second</mark> Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
 Temperature Minimum (T_s MIN) 	N/A	
- Temperature Typical (T _s TYP)	150°C	
	N/A	
- Time (t _s MIN)	60 - 120 Seconds	
Ramp-up Rate (T _L to T _P)	5°C/Second Maximum	
Time Maintained Above:		
- Temperature (T _L)	150°C	
- Time (t∟)	200 Seconds Maximum	
Peak Temperature (T _P)	240°C Maximum	
Target Peak Temperature(T _P Target)	240°C Maximum 2 Times/230°C Maximum 1Time	
Time within 5°C of actual peak (t _p)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5° <mark>C/Second</mark> Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)